


BRITISH STANDARDS INSTITUTION

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BS CECC 90103 - 011

ISSUE 1

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**ELECTRONIC COMPONENTS OF ASSESSED QUALITY
DETAIL SPECIFICATION IN ACCORDANCE WITH:**

 BS CECC 90 000 : 1976
BS CECC 90 100 : 1977

MANUFACTURERS TYPE NUMBER

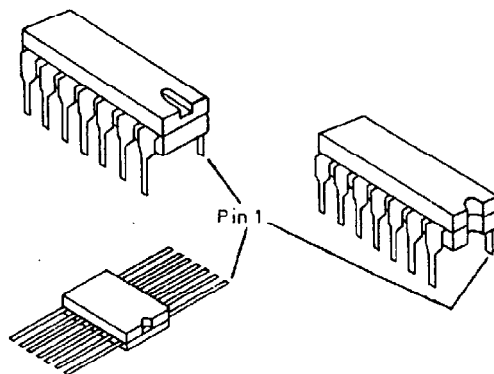
 54LS12
64LS12
74LS12
84LS12

 SEE PD 9002 AND CECC 00 200
For ordering information see
clause 1

**TRIPLE 3-INPUT NAND GATES
WITH OPEN COLLECTOR OUTPUTS**

 TYPICAL CONSTRUCTION
SILICON MONOLITHIC
BIPOLAR TTL-LOW-POWER
SCHOTTKY

ASSESSMENT LEVELS
R, S, T AND V

 Outline not to scale: Isometric projection
Marking information see clause 1

 Refer to IEC 191-1-50a (type A50B)
Dual-in-Line (plastic or ceramic)
refer to Appendix A1.3
Flatpack (metal or ceramic)

1. Type description
1.1 Truth table (each gate)

INPUTS			OUTPUT
A	B	C	Y
H	H	H	L
L	X	X	H
X	L	X	H
X	X	L	H

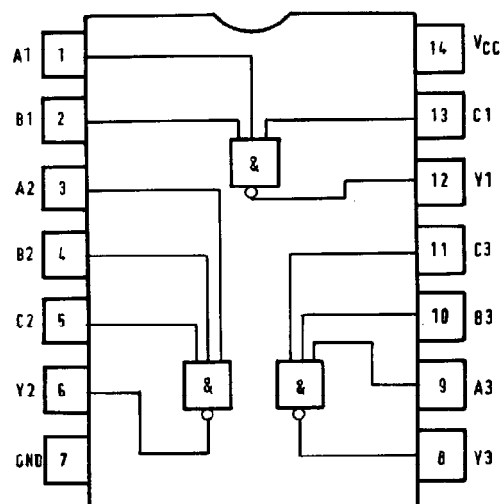
 Refer to Qualified Products List PD 9002 and/or CECC 00 200
for details of manufacturers approved to this specification

1.1.1 Boolean equation

$$Y = \overline{A.B.C.}$$

1.2 Terminal identification, type designation and marking

1.2.1 Terminal identification



Three 3-input Nand gates
with open collector outputs

1.2.2 Type designation

TEMPERATURE RANGE	PACKAGE		
	Ceramic Dual-in-Line	Plastic Dual-in-Line	Ceramic Flatpack
0 + 70	74LS12J	N	W
-25 + 85	84LS12J		
-40 + 85	64LS12J		
-55 +125	54LS12J		

1.2.3 Marking

Each integrated circuit shall bear the following markings:

- (1) Terminal identification
- (2) Type designation
- (3) Date code
- (4) Factory identification code (unless derived from trademark)
- (5) Manufacturers trade name or mark
- (6) Mark of conformity (unless a certificate of conformity is used)

1.3 Ordering information

Orders for these integrated circuits shall contain the following minimum information.

Manufacturers integrated circuit type designation screening procedure and assessment levels as detailed to this CECC specification number.

(For details of screening procedures see Appendix A1.1)

2. Limiting conditions of use (not for inspection purposes)

2.1	Maximum continuous supply voltage	V_{CC}	-0,5V +7,0V				
2.2	Maximum input voltage	V_I	-0,5V +7,0V				
				54LS	64LS	74LS	84LS
2.3	Minimum and maximum operating ambient temperatures	$T_{amb}(^{\circ}C)$	min. -55 max. +125	-40 +85	0 +70	-25 +85	
2.4	Minimum and maximum storage temperatures	$T_{stg}(^{\circ}C)$	min. -65 max. +150	(All types)			

3. Recommended operating conditions and associated characteristics (not for inspection purposes)

3.1 Recommended operating conditions.

These apply over the operating ambient temperature range unless otherwise stated.

Description	Symbol	Type	Value	Unit
Positive supply voltage range	V_{CC}	54LS 64/74/84LS	4,5 - 5,5 4,75 - 5,25	V V
Minimum value of High level input voltage	V_{IHB}	All types	2,0	V
Maximum value of High level input voltage	V_{IHA}	All types	5,5	V
Minimum value of Low level input voltage	V_{ILB}	All types	-0,3	V
Maximum value of Low level input voltage	V_{ILA}	54LS 64/74/84LS	0,7 0,8	V V
Maximum value of Low level output current for each output	I_{OLA}	54LS 64/74/84LS	4,0 8,0	mA mA
Maximum value of output current for each output at V_{OH}	$-I_{OHX}$	All types	100,0	μA
Maximum value of applied off-state output voltage	V_{OZA}	All types	5,5	V

3.2 Associated characteristics

3.2.1 Minimum and maximum values are given for the worst case operation over the ambient temperature range, except for those conditions marked with an asterisk (*)

	54LS	64LS	74LS	84LS	
T _{amb} min.	-55	-40	0	-25	°C
T _{amb} max.	+125	+85	+70	+85	
V _{CC} min.	4,5	4,75			V
V _{CC} max.	5,5	5,25			

3.2.2

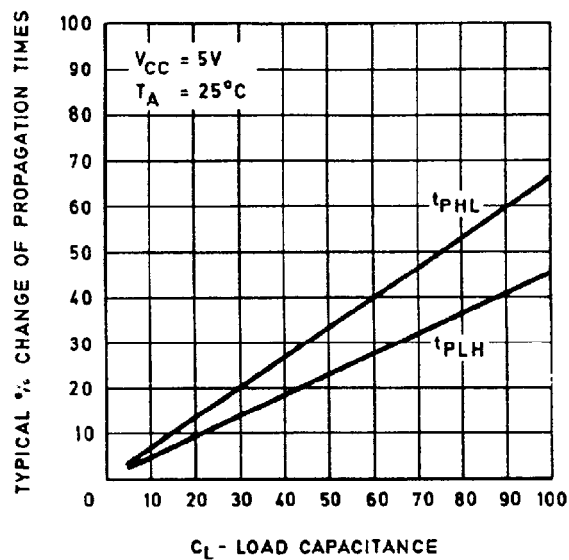
Characteristics	Conditions	$V_{CC}(\text{V})$	Symbol	Min.	Max.	Unit
Total supply current with High level output	$V_{IL} = 0\text{V}$ (1)	V_{CC} max.	I_{CCH}	-	1,4	mA
Total supply current with Low level output	$V_{IH} = 4,5\text{V}$	V_{CC} max.	I_{CCL}	-	3,3	mA
High level input current	$V_{IH(1)} = 7,0\text{V}$	V_{CC} max.	$I_{IH(1)}$	-	100,0	μA
	$V_{IH(2)} = 2,7\text{V}$	V_{CC} max.	$I_{IH(2)}$	-	20,0	μA
Low level input current	$V_{IL} = 0,4\text{V}$	V_{CC} max.	$-I_{IL}$	-	0,4	mA
Input clamping voltage	$-I_{IC} = 18,0\text{mA}$	V_{CC} min.	$-V_{ICA}$	-	1,5	V
Output voltage All types 64/74/84LS	$I_{OL(1)} = 4,0\text{mA}$ (2)	V_{CC} min.	$V_{OL(1)}$	-	0,4	V
	$I_{OL(2)} = 8,0\text{mA}$ (3)		$V_{OL(2)}$	-	0,5	V
Propagation time All types	$T_{amb} = 25^{\circ}\text{C}^*$ test conditions as in Sub-group A5	5,0V	t_{PHL}	-	28,0	ns
			t_{PLH}	-	32,0	ns

(1) To all inputs, (2) Fan out = 10, (3) Fan out = 20,

* See 3.2.1 of this specification

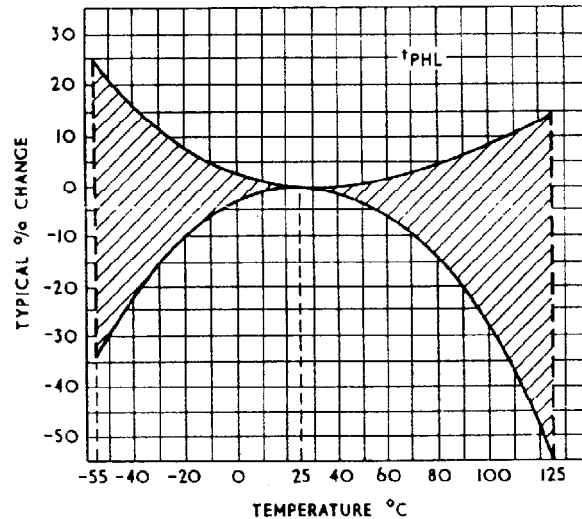
3.3 Supplementary information

3.3.1 Change of typical propagation time with output loading

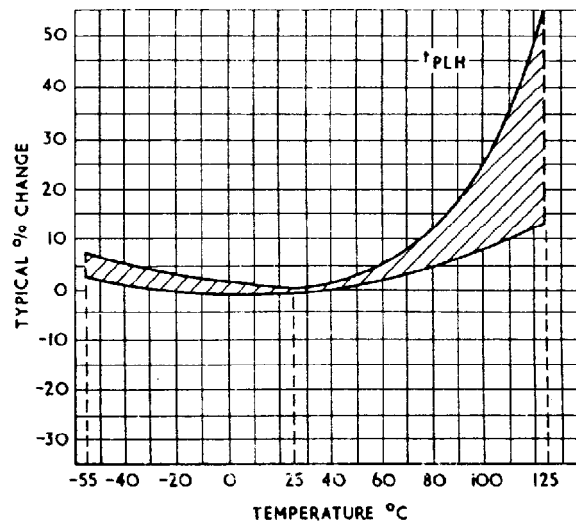


Propagation times Vs. load capacitance

3.3.2 Variation of propagation time with temperature



3.3.2 Variation of propagation time with temperature (contd)



3.3.3 D.C. noise levels

$$\text{Low level } V_{\text{OHB}} - V_{\text{IHB}} = V_{\text{NL}}$$

3.4 Typical values* ($V_{\text{CC}} = 5.0\text{V}^*$, $T_{\text{amb}} = 25^\circ\text{C}$)

typical supply current of the device (50% duty cycle)

$$\text{LS21 } I_{\text{CC}} = 1.26\text{mA}$$

Typical propagation time:

$$\text{LS12 } t_{\text{Ptyp}} = \frac{t_{\text{PLH}} + t_{\text{PHL}}}{2} = 16.0\text{ns}$$

*See 3.2 of this specification

4. Inspection Requirements

All tests shall be performed at $T_{\text{amb}} = 25^\circ\text{C} \pm 5^\circ\text{C}$ unless otherwise stated.

The clause numbers refer to the sectional specification CECC 90100, if not otherwise stated.

The tests in the tables shall be applied to each gate of multiple gate devices.